

August 1998 Revised April 2000

GTLP16T1655 16-Bit LVTTL/GTLP Universal Bus Transceiver

General Description

The GTLP16T1655 is a 16-bit universal bus transceiver that provides LVTTL to GTLP signal level translation. It allows for transparent, latched and clocked modes of data transfer. The device provides a high speed interface between cards operating at LVTTL logic levels and a backplane operating at GTLP logic levels. High speed backplane operation is a direct result of GTLP's reduced output swing (<1V), reduced input threshold levels and output edge rate control. The edge rate control minimizes bus settling time. GTLP is a Fairchild Semiconductor derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD8-3.

Fairchild's GTLP has internal edge-rate control and is process, voltage, and temperature (PVT) compensated. Its function is similar to BTL and GTL but with different output levels and receiver threshold. GTLP output LOW level is typically less than 0.5V, the output level HIGH is 1.5V and the receiver threshold is 1.0V.

Features

- Bidirectional interface between GTLP and LVTTL logic levels
- Variable Edge Rate Control pin to select desired edge rate on the GTLP backplane (V_{ERC})
- Partitioned as two 8-Bit transceivers with individual latch timing and output control but with a common clock.
- Power up/down high impedance for live insertion.
- External pin to pre-condition I/O capacitance to high state
- Bus-hold data inputs on the A-Port eliminates the need for external pull-up resistors on unused inputs
- LVTTL compatible driver and control inputs
- Flow through pinout optimizes PCB layout
- Open drain on GTLP to support wired-or connection
- A Port source/sink -24 mA/+24 mA
- B Port sink +100mA
- D-type flip-flop, latch and transparent data paths
- -40°C to 85°C Temperature capability
- Available in TSSOP

Ordering Code:

Order Number	Package Number	Package Description
GTLP16T1655MTD	MTD64	64-Lead Thin Shrink Small Outline Package, JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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DS500172

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Connection Diagram

		_	
1OEAB-	1	64	-CLK
10EBA-	2	63	-1LEAB
Vcc-	3	62	-1LEBA
1A1-	4	61	-V _{ERC}
GND-	5	60	-GND
1A2-	6	59	−1B1
1A3-	7	58	-1B2
GND-	8	57	-GND
1A4-	9	56	-1B3
GND-	10	55	– 1B4
1A5-	11	54	– 1B5
GND-	12	53	-GND
1A6-	13	52	−1B6
1A7-	14	51	-1B7
Vcc-	15	50	-Vcc
1A8-	16	49	-1B8
2A1-	17	48	-2B1
GND-	18	47	-GND
2A2-	19	46	-2B2
2A3-	20	45	-2B3
GND-	21	44	-GND
2A4-	22	43	-2B4
2A5-	23	42	-2B5
GND-	24	41	-V _{REF}
2A6-	25	40	-2B6
GND-	26	39	-GND
2A7-	27	38	-2B7
Vcc-	28	37	-2B8
2A8-	29	36	-Vccbias
GND-	30	35	-2LEAB
2OEAB-	31	34	-2LEBA
2OEBA-	32	33	-OE
			•

Pin Descriptions

Pin Names	Description
1 OEAB	A-to-B Output Enable (Active LOW)
2OEAB	Byte 1 and Byte 2
1 OEBA	B-to-A Output Enable (Active LOW)
2OEBA	Byte 1 and Byte 2
ŌE	Disables all I/O ports simultaneously
1LEAB	A-to-B Latch Enable (Transparent HIGH)
2LEAB	Byte 1 and Byte 2
1LEBA	B-to-A Latch Enable (Transparent HIGH)
2LEBA	Byte 1 and Byte 2
V_{REF}	GTLP Reference Voltage
CLK	A-to-B and B-to-A Clock
1A1-1A8	A Port I/O Byte 1 and Byte 2
2A1-2A8	
1B1-1B8	B Port I/O Byte 1 and Byte 2
2B1-2B8	

Truth Tables

(Note 1)

	Inpu	ts		Output	Mode
CEAB	LEAB	CLK	Α	В	Wode
Н	Х	Х	Х	Z	High Impedance
L	Н	Χ	L	L	Transparent
L	Н	Χ	Н	н	Transparent
L	L	\uparrow	L	L	Registered
L	L	\uparrow	Н	н	Registered
L	L	Н	X	B ₀ (Note 2)	Previous State
L	L	L	X	B ₀ (Note 3)	Previous State

Inputs			Outputs	
OE	OEAB	OEBA	A Port	B Port
L	L	L	Active	Active
L	L	Н	Z	Active
L	Н	L	Active	Z
L	Н	Н	Z	Z
н	X	X	7	7

Inputs	Output Edge
V _{ERC}	B Port
V _{CC}	Slow
GND	Fast

Note 1: A-to-B data flow is shown. B-to-A data flow is similar but uses $\overline{\text{OEBA}}$, LEBA, CLK.

Note 2: Output level before the indicated steady state input conditions were established, provided CLK was HIGH prior to LEAB going LOW.

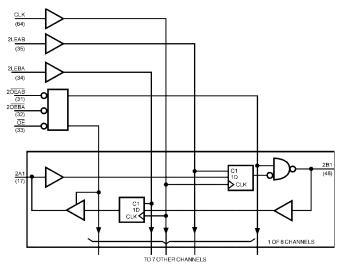
 $[\]textbf{Note 3:} \ \ \textbf{Output level before the indicated steady state input conditions were established.}$

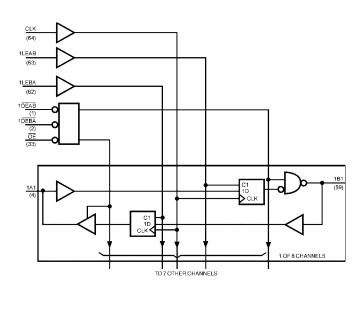
Functional Description

The GTLP16T1655 is a high drive (100 mA) 16-bit universal bus transceiver containing D-type flip-flop, latch and transparent modes of operation for the data path. The device is uniquely partitioned as two 8-bit transceivers with individual latch timing and output control signals but with a common clock pin (CLK) for both transceiver words. Data flow for each word is determined by the respective latch enables (xLEAB and xLEBA), output enables (xOEAB and xOEBA) and clock (CLK). The output enables (10EAB, 10EBA, and 20EAB and 20EBA) control Byte1 and Byte2 data for the A to B and B to A directions respectively.

For A-to-B data flow, the devices operate in the transparent mode when LEAB is HIGH. When LEAB transitions LOW, the A data is latched independent of CLK HIGH or LOW. If LEAB is LOW the A data is registered on the CLK LOW-to-HIGH transition. When \overline{OEAB} is LOW the outputs are active. With \overline{OEAB} HIGH the outputs are HIGH impedance. Data flow for the B-to-A direction is identical but uses \overline{OEBA} , LEBA and CLK. Note that CLK is common to both directions and both 8-bit words. \overline{OE} is also common and is used to disable all I/O ports simultaneously.

Logic Diagrams





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Absolute Maximum Ratings (Note 4) -0.5V to +4.6V Supply Voltage (V_{CC}) DC Input Voltage (V_I) -0.5V to +4.6V DC Output Voltage (V_O) Outputs 3-STATE -0.5V to +4.6VOutputs Active (Note 5) -0.5V to +4.6VDC Output Sink Current into A Port I_{OL} 48 mA DC Output Source Current from A Port I_{OH} -48 mA DC Output Sink Current into B Port in the LOW State, $I_{\rm OL}$ 200 mA (Note 6) DC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA DC Output Diode Current (I_{OK}) $V_O < 0V$ -50 mA $V_O > V_{CC}$ +50 mA **ESD** Rating >2000V Storage Temperature (T_{STG}) -65°C to +150°C

Recommended Operating Conditions

Supply Voltage V _{CC}	3.0V to 3.6V
Bus Termination Voltage (V _{TT})	
GTLP	1.35V to 1.65V
GTL	1.14V to 1.26V
V_{REF}	
GTLP	0.87V to 1.1V
GTL	0.74V to 0.87V
Input Voltage (V _I)	
on A Port and Control Pins	0.0V to $V_{\mbox{\footnotesize CC}}$
on B Port	0.0V to V_{tt}
HIGH Level Output Current (IOH)	
A Port	−24 mA
LOW Level Output Current (I _{OL})	
A Port	+24mA
B Port	+100 mA
Operating Temperature (T _A)	-40°C to $+85^{\circ}\text{C}$
Note 4: The Absolute Maximum Ratings are those the safety of the device cannot be guaranteed. The	

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: V_{TT} and R_{term} can be adjusted to accommodate backplane impedances other than 50Ω , within the boundaries of not exceeding the DC Absolute I_{OL} ratings (200 mA). Similarly V_{REF} can be adjusted to compensate for changes in V_{TT} .

DC Electrical Characteristics

Over Recommended Operating Free-Air Temperature Range, $V_{REF} = 1.0V$ (unless otherwise noted).

Symbol		Test Conditions		Min	Typ (Note 7)	Max	Units	
V _{IH}	B Port			V _{REF} +0.05		V _{TT}	V	
	Others			2.0			V	
V _{IL}	B Port			0.0		V _{REF} -0.05	V	
	Others					0.8	V	
V _{REF}	GTLP			0.74	1.0	1.1	V	
V _{IK}		V _{CC} = 3.0V	$I_I = -18 \text{ mA}$			-1.2	V	
V _{OH}	A Port	V _{CC} = Min to Max (Note 8)	$I_{OH} = -100 \mu\text{A}$	V _{CC} -0.2				
		V _{CC} = 3.0V	$I_{OH} = -12 \text{ mA}$	2.4			V	
			$I_{OH} = -24 \text{ mA}$	2.2				
V _{OL}	A Port	V _{CC} = Min to Max (Note 8)	$I_{OL} = 100 \mu A$			0.20		
		V _{CC} = 3.0V	I _{OL} = 12 mA			0.40	V	
			$I_{OL} = 24 \text{ mA}$			0.50		
	B Port	V _{CC} = 3.0V	I _{OL} = 40 mA			0.20	V	
			$I_{OL} = 80 \text{ mA}$			0.40		
			I _{OL} = 100 mA			0.50		
I _I	A Port	V _{CC} = 3.6V	V _I = V _{CC} or 0V			±10	μА	
	Control Pins		V _I = V _{CC} or 0V			±10	μА	
	B Port	V _{CC} = 3.6V	V _I = V _{TT} or GND			±10	<u>.</u> μΑ	
I _{OFF}	Except	V _{CC} = 0	V_1 or $V_0 = 0$ to			100		
0	V _{ERC}		V _{CC}				μΑ	
I _{I(hold)}	A Port	V _{CC} = 3.0V	V _I = 0.8V	75				
.()			V _I = 2.0V	-75			μΑ	
		V _{CC} = 3.6V	$V_I = 0$ to V_{CC}			±500		
I _{OZH}	A Port	V _{CC} = 3.6V	$V_O = V_{CC}$			10		
	B Port		V _O = 1.5V			10	μΑ	
l _{OZL}	A Port	V _{CC} = 3.6V	V _O = 0V			-10		
	B Port		V _O = 0.4V			-10	μА	
I _{OZPU}	A Port	V _{CC} = 0 to 1.5V	V _O = 0.5 to 3V			±50	μΑ	
(Note 9)		OE = 0 or V _{CC}						
I _{OZPD}	A Port	V _{CC} = 1.5 to 0V	V _O = 0.5 to 3V			±50	μΑ	
(Note 9)		$\overline{OE} = 0$ or V_{CC}						
I _{CC}	A or B Ports	V _{CC} = 3.6	Outputs HIGH			55		
(v _{cc})		$I_{O} = 0$	Outputs LOW			55	mA	
		$V_I = V_{CC}$ or GND	Outputs Disabled			55		
Δl _{CC}	A Port and	V _{CC} = 3.6V	One Input at		0	1		
(Note 10)	Control Pins	A or Control	V _{CC} -0.6				mA	
		Inputs at V _{CC} or GND						
C _i	Control Pins		$V_I = V_{CC}$ or 0		5.8	7.0		
	A Port		$V_I = V_{CC}$ or 0		8.0	9.5	pF	
	B Port		$V_1 = V_{CC}$ or 0		8.3	9.9	-	

Note 7: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25^{\circ}C$.

Note 8: For conditions shown as Min or Max, use the appropriate value specified under recommended operating conditions.

 $\textbf{Note 9:} \ \textbf{This is specified by characterization but not tested}.$

 $\textbf{Note 10:} \ \ \textbf{This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} \ or \ GND.$

Live Insertion Characteristics

Over Recommended Operating Free-Air Temperature Range, $V_{REF} = 1.0V$ (unless otherwise noted).

Para	meter	Test Conditions		Min	Тур	Max	Units
I _{CC}	B Port	V _{CC} = 0 to 3V	V _O = 0 to 1.2V			5	mA
(V _{CC} BIAS)		$V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	$V_I (V_{CC}BIAS) = 3 \text{ to } 3.6V$			10	μΑ
Vo	B Port	$V_{CC} = 0$ $V_{I} (V_{CC}BIAS) = 3.3v$			1.1		V
Io	B Port	$V_{CC} = 0$ $V_{I} (V_{CC}BIAS) = 3 \text{ to } 3$	$V_{CC} = 0$ $V_1 (V_{CC}BIAS) = 3 \text{ to } 3.6V$ $V_0 = 0.4$				
		$V_{CC} = 0 \text{ to } 3.6V \qquad \overline{OE} = 3.3V$				100	μΑ
		$V_{CC} = 0$ to 1.5V $\overline{OE} = 0$ to 3.3	V			100	

AC Operating Requirements (GTLP)

Over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5V$ and $V_{ref} = 1.0V$ (unless otherwise noted).

	Parameter			Max	Unit
f _{CLOCK}	Max Clock Frequency		0	160	MHz
t _{WIDTH}	Pulse Duration	LE HIGH	3.0		
		CLK HIGH or LOW	3.0		ns
t _{SU}	Setup Time	Data before CLK↑	2.5		
		Data before LE↓ (CLK = X)	2.5		ns
t _{HOLD}	Hold Time	Data after CLK↑	0.5		
		Data after LE↓ (CLK = X)	0.5		ns

B to A AC Electrical Characteristics (GTLP)

Over recommended range of supply voltage and operating free-air temperature, $V_{REF} = 1.0V$, $V_{TT} = 1.5V$, $V_{ERC} = V_{CC}$ or GND (unless otherwise noted). $C_L = 30$ pF for B-Port and $C_L = 50$ pF for A-Port.

Parameter	From (Input)	To (Output)	Min	Typ (Note 11)	Max	Unit
f _{MAX}			160			MHz
t _{PLH}	В	А	1.0		4.7	
t _{PHL}			1.5		4.8	ns
t _{PLH}	LEAB	А	1.2		4.0	
t _{PHL}			1.2		3.8	ns
t _{PLH}	CLK	А	1.2		4.0	
t _{PHL}			1.2		4.0	ns
t _{PLZ/HZ}	ŌĒ	А	1.4		4.5	
t _{PZH/ZL}			1.0		4.0	ns
t _{PLZ/HZ}	OEBA	А	1.2		4.9	
t _{PZH/ZL}			1.0		4.0	ns

Note 11: All typical values are at $V_{CC}=3.3V$, and $T_A=25^{\circ}C$.

A to B AC Electrical Characteristics (GTLP)

Over recommended range of supply voltage and operating free air temperature, V = 1.0V, $V_{TT} = 1.5V$ (unless otherwise noted). $C_L = 30$ pF for B-Port and $C_L = 50$ pF for A-Port.

Symbol	From (Input)	To (Output)	Min	Type (Note 12)	Max	Units
f _{MAX}			160			MHz
t _{PLH}	А	В	2.6		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		0.8		4.5	ns
t _{PLH}	A	В	2.0		4.9	
t _{PHL}	V _{ERC} = GND		0.7		4.0	ns
t _{PLH}	LEAB	В	2.6		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		0.8		4.0	ns
t _{PLH}	LEAB	В	2.2		4.9	
t _{PHL}	V _{ERC} = GND		0.7		4.0	ns
t _{PLH}	CLK	В	2.8		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		1.0		4.0	ns
t _{PLH}	CLK	В	2.3		5.0	
t _{PHL}	V _{ERC} = GND		0.8		4.0	ns
t _{PLH}	ŌĒ	В	2.7		5.8	
t _{PHL}	V _{ERC} = V _{CC}		0.6		4.0	ns
t _{PLH}	ŌĒ	В	2.1		4.9	
t _{PHL}	V _{ERC} = GND		1.0		4.0	ns
t _{PLH}	OEAB	В	2.6		5.8	
t _{PHL}	V _{ERC} = V _{CC}		0.6		4.0	ns
t _{PLH}	OEAB	В	2.0		4.9	
t _{PHL}	V _{ERC} = GND		0.6		3.5	ns
t _{FALL/RISE} V _{ERC} = V _{CC}	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	2.0/2.5		ns
t _{FALL/RISE} V _{ERC} = GND	Transition Time, B out	puts (0.6V to 1.3V)	0.7/0.7	1.5/2.0		ns

Note 12: All Typical values are at V_{CC} = 3.3V and T_A = 25°C

Extended Electrical Characteristics (GTLP)

Over recommended ranges of supply voltage and operating free-air temperature $V_{REF} = 1.0V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From (Input)	To (Output)	Min	Typ (Note 13)	Max	Unit
t _{OSLH} (Note 14)	Α	В		0.4	1.0	ns
t _{OSHL} (Note 14)				0.4	1.0	ns
t _{PV(HL)} (Note 15) (Note 16)	A	В			1.5	ns
t _{OSLH} (Note 14)	CLKAB	В		0.3	0.9	ns
t _{OSHL} (Note 14)				0.3	0.6	ns
t _{PV(HL)} (Note 15) (Note 16)	CLKAB	В			1.2	ns
t _{OSLH} (Note 14)	В	A		0.3	1.0	ns
t _{OSHL} (Note 14)				0.3	1.0	ns
t _{OST} (Note 14)	В	A		0.6	1.5	ns
t _{PV} (Note 15)	В	A			1.6	ns
t _{OSLH} (Note 14)	CLKAB	A		0.3	0.6	ns
t _{OSHL} (Note 14)				0.3	0.6	ns
t _{OST} (Note 14)	CLKAB	A		0.5	1.0	ns
t _{PV} (Note 15)	CLKAB	A			1.1	ns

Note 13: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25$ °C.

Note 14: t_{OSHL}/t_{OSLH} and t_{OST}—Output to output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs within the same packaged device. The specifications are given for specific worst case V_{CC} and temperature and apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST}). This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.

Note 15: t_{PV}—Part to part skew is defined as the absolute value of the difference between the actual propagation delay for all outputs from device to device. The parameter is specified for a specific worst case V_{CC} and temperature. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.

Note 16: Due to the open drain structure on GTLP outputs, t_{OST} and $t_{PV(LH)}$ in the A-to-B direction are not specified. Skew on these paths is dependent on the V_{TT} and R_T values on the backplane.

AC Operating Requirements (GTL)

Over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.2V$ and $V_{ref} = 0.8V$ (unless otherwise noted).

Parameter			Min	Max	Units
f _{CLOCK}	Max Clock Frequency		0	160	MHz
t _{WIDTH}	Pulse Duration	LE HIGH	3.0		ns
		CLK HIGH or LOW	3.0		ns
t _{SU}	Setup Time	Data before CLK↑	2.5		ns
		Data before LE↓ (CLK = X)	2.5		115
t _{HOLD}	Hold Time	Data after CLK↑	0.5		ns
		Data after LE↓ (CLK =X)	0.5		115

B to A AC Electrical Characteristics (GTL)

Over recommended range of supply voltage and operating free air temperature, $V_{ref} = 0.8V$, $V_{TT} = 1.2V$, $V_{ERC} = V_{CC}$ or GND (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Parameter	From (Input)	To (Output)	Min	Typ (Note 17)	Max	Units	
f _{MAX}			160			MHz	
t _{PLH}	В	Α	1.0		4.7		
t _{PHL}			1.2		4.8	ns	
t _{PLH}	LEBA	А	1.0		4.4		
t _{PHL}			1.1		4.0	ns	
t _{PLH}	CLK	А	1.0		4.2		
t _{PHL}			1.1		4.1	ns	
t _{PLZ/HZ}	ŌE	А	1.5		4.6		
t _{PZH/ZL}			1.2		4.2	ns	
t _{PLZ/HZ}	 OEBA	А	1.2		4.9		
t _{PZH/ZL}			1.0		4.0	ns	

Note 17: All Typical values are at $V_{CC} = 3.3 V$ and $T_A = 25 ^{\circ} C$.

Over recommended range of supply voltage and operating free air temperature, $V_{REF} = 0.8V$, $V_{TT} = 1.2V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From (Input)	To (Output)	Min	Typ (Note 18)	Max	Units
f _{MAX}			160			MHz
t _{PLH}	Α	В	2.2		5.7	
t _{PHL}	$V_{ERC} = V_{CC}$		1.0		4.7	ns
t _{PLH}	Α	В	1.5		4.8	
t _{PHL}	V _{ERC} = GND		0.9		4.0	ns
t _{PLH}	LEAB	В	2.2		5.7	
t _{PHL}	V _{ERC} = V _{CC}		1.0		4.1	ns
t _{PLH}	LEAB	В	1.7		5.0	
t _{PHL}	V _{ERC} = GND		0.9		4.4	ns
t _{PLH}	CLK	В	2.8		5.8	
t _{PHL}	V _{ERC} = V _{CC}		1.0		4.3	ns
t _{PLH}	CLK	В	2.3		5.0	
t _{PHL}	V _{ERC} = GND		1.0		4.3	ns
t _{PLH}	ŌĒ	В	2.5		5.8	
t _{PHL}	V _{ERC} = V _{CC}		0.8		4.3	ns
t _{PLH}	ŌĒ	В	1.7		4.9	
t _{PHL}	V _{ERC} = GND		0.9		4.3	ns
t _{PLH}	OEAB	В	2.2		5.8	
t _{PHL}	V _{ERC} = V _{CC}		0.8		4.3	ns
t _{PLH}	OEAB	В	1.7		4.9	
t _{PHL}	V _{ERC} = GND		0.9		3.8	ns
t _{FALL/RISE} V _{ERC} = V _{CC}	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	2.0/2.5		ns
t _{FALL/RISE} V _{ERC} = V _{CC}	Transition Time, B outputs (0.6V to 1.3V)		0.7/0.7	1.5/2.0		ns

Note 18: All Typical values are at $V_{CC} = 3.3V$ and $T_A = 25^{\circ}C$.

Extended Electrical Characteristics (GTL)

Over recommended ranges of supply voltage and operating free-air temperature $V_{REF} = 0.8V$ (unless otherwise noted). $C_L = 30$ pF for B Port and $C_L = 50$ pF for A Port.

Symbol	From (Input)	To (Output)	Min	Typ (Note 19)	Max	Unit
t _{OSLH} (Note 20)	A	В		0.4	1.0	ns
t _{OSHL} (Note 20)				0.4	1.0	ns
t _{PV(HL)} (Note 21) (Note 22)	A	В			1.5	ns
t _{OSLH} (Note 20)	CLKAB	В		0.3	0.9	ns
t _{OSHL} (Note 20)				0.3	0.6	ns
t _{PV(HL)} (Note 21) (Note 22)	CLKAB	В			1.2	ns
t _{OSLH} (Note 20)	В	Α		0.3	1.0	ns
t _{OSHL} (Note 20)				0.3	1.0	ns
t _{OST} (Note 20)	В	A		0.6	1.5	ns
t _{PV} (Note 21)	В	Α			1.6	ns
t _{OSLH} (Note 20)	CLKAB	A		0.3	0.6	ns
t _{OSHL} (Note 20)				0.3	0.6	ns
t _{OST} (Note 20)	CLKAB	Α		0.5	1.0	ns
t _{PV} (Note 21)	CLKAB	Α			1.1	ns

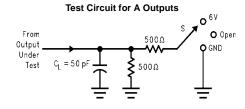
Note 19: All typical values are at $V_{CC} = 3.3V$, and $T_A = 25$ °C.

Note 20: t_{OSHL}/t_{OSLH} and t_{OST}—Output to output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs within the same packaged device. The specifications are given for specific worst case V_{CC} and temperature and apply to any outputs switching in the same direction either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}) or in opposite directions both HL and LH (t_{OST)}. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTL outputs could vary on the backplane due to the loading and impedance seen by the design.

Note 21: t_{PV}—Part to part skew is defined as the absolute value of the difference between the actual propagation delay for all outputs from device to device. The parameter is specified for a specific worst case V_{CC} and temperature. This parameter is guaranteed by design and statistical process distribution. Actual skew values between the GTL outputs could vary on the backplane due to the loading and impedance seen by the device.

Note 22: Due to the open drain structure on GTL outputs, t_{OST} and $t_{PV(LH)}$ in the A-to-B direction are not specified. Skew on these paths is dependent on the V_{TT} and R_T values on the backplane.

Test Circuits and Timing Waveforms

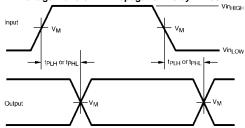


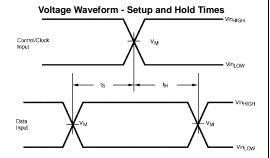
 $\begin{tabular}{lll} \textbf{Test} & \textbf{S} \\ t_{PLH}/t_{PHL} & Open \\ t_{PLZ}/t_{PZL} & 6V \\ t_{PHZ}/t_{PZH} & GND \\ \end{tabular}$

Test Circuit for B Outputs 1.5V (GTLP) 1.2V (GTL) From Output Under Test 30 pF

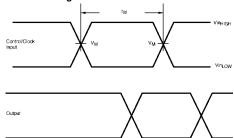
Note A: C_L includes probes and Jig capacitance. Note B: For B-Port, C_L = 30 pF is used fort worst case.

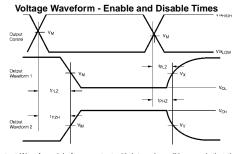
Voltage Waveform - Propagation Delay Times





Voltage Waveform - Pulse Width





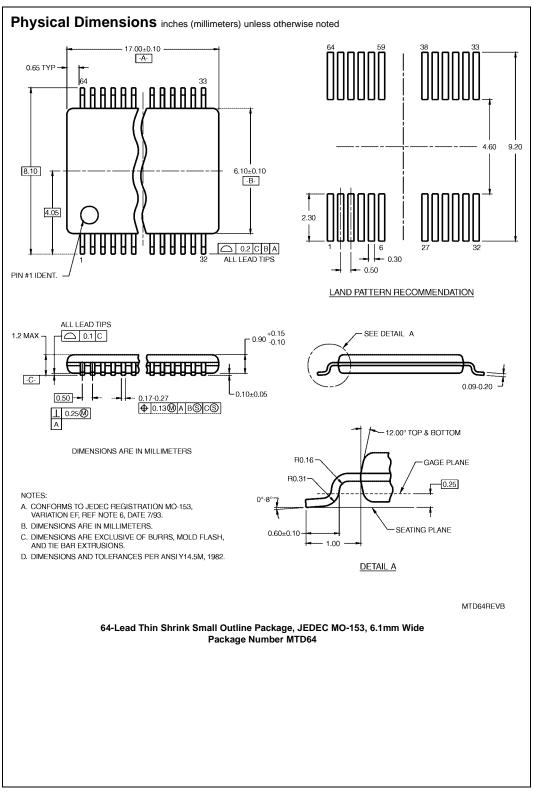
Output Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the control output

Output Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the control output

Input and Measure Conditions

	A or LVTTL Pins	B or GTLP Pins
V_{inHIGH}	3.0	1.5
V_{inLOW}	0.0	0.0
V _M	1.5	1.0
V _X	V _{OL} + 0.3V	N/A
V _Y	V _{OH} – 0.3V	N/A

All input pulses have the following characteristics: Frequency = 10MHz, t_{RISE} = t_{FALL} = 2 ns, Z_0 = 50Ω The outputs are measured one at a time with one transition per measurement



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